SUPPLEMENTARY DATA

Study by electrical conductivity measurements of semiconductive and redox properties of Nb-doped NiO catalysts in correlation with the oxidative dehydrogenation of ethane

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Catalyst	T = 350 °C			$T = 400 \ ^{\circ}C$		
	C ₂ H ₆	Reaction rate	C_2H_4	C_2H_6	Reaction rate	C_2H_4
	conversion	(µmol m ⁻² s ⁻¹)	selectivity	conversion	(µmol m ⁻² s ⁻¹)	selectivity
	(%)		(%)	(%)		(%)
NiO	6.3	0.11	21.0	18.4	0.35	29.0
Nb(1)NiO	11.0	0.11	52.2	26.5	0.28	58.0
Nb(5)NiO	12.7	0.08	73.0	30.2	0.19	72.3
Nb(10)NiO	10.2	0.05	82.8	25.6	0.11	80.0
Nb(15)NiO	14.5	0.03	87.8	36.0	0.08	82.6
Nb(20)NiO	13.7	0.04	83.0	33.0	0.09	78.3

Table S1. Catalytic reaction data of the Nb-doped NiO catalysts in the oxidative dehydrogenation of ethane (reaction conditions: W/F = 0.24 g s cm⁻³, $C_2H_6/O_2 = 2/1$) [1].

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